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Team Nexperia

74HC1G00; 74HCT1G00

2-input NAND gate

Rev. 5 — 25 September 2013

Product data sheet

1. General description

The 74HC1G00; 74HCT1G00 is a single 2-input NAND gate. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of $V_{\rm CC}$.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
 - ◆ For 74HC1G00: CMOS level
 - ◆ For 74HCT1G00: TTL level
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from −40 °C to +85 °C and −40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

Type number Package						
	Temperature range	Name	Description	Version		
74HC1G00GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads;	SOT353-1		
74HCT1G00GW			body width 1.25 mm			
74HC1G00GV	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753		
74HCT1G00GV						



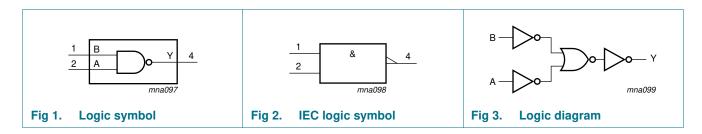
4. Marking

Table 2. Marking codes

Type number	Marking[1]
74HC1G00GW	НА
74HCT1G00GW	TA
74HC1G00GV	H00
74HCT1G00GV	T00

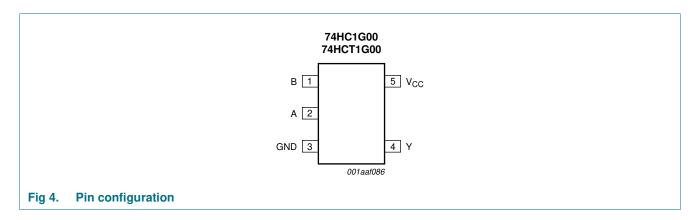
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
В	1	data input
Α	2	data input
GND	3	ground (0 V)
Υ	4	data output
V _{CC}	5	supply voltage

74HC_HCT1G00

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7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level

Input		Output
Α	В	Υ
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V). [1]

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±12.5	mA
I _{CC}	supply current		-	25	mA
I_{GND}	ground current		-25	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2] _	200	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter		74HC10	G00		74HCT	Unit		
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
V _O	output voltage		0	-	V_{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
	and fall rate	$V_{CC} = 4.5 \text{ V}$	-	-	139	-	-	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V

^[2] Above 55 °C, the value of P_{tot} derates linearly with 2.5 mW/K.

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

Symbol	Parameter	Conditions	-40	°C to +	85 °C	-40 °C	Unit	
			Min	Тур	Max	Min	Max	
For type	74HC1G00		'		'	'	'	
V _{IH}	HIGH-level input	$V_{CC} = 2.0 \text{ V}$	1.5	1.2	-	1.5	-	٧
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	٧
		$V_{CC} = 6.0 \text{ V}$	4.2	3.2	-	4.2	-	٧
V _{IL}	LOW-level input	$V_{CC} = 2.0 \text{ V}$	-	0.8	0.5	-	0.5	٧
	voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	٧
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.8	-	1.8	٧
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}						
	voltage	$I_O = -20 \mu A$; $V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	٧
		$I_O = -20 \mu A$; $V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	٧
		$I_O = -20 \mu A$; $V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	٧
		$I_{O} = -2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.13	4.32	-	3.7	-	٧
		$I_{O} = -2.6 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.63	5.81	-	5.2	-	٧
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}						
	voltage	$I_O = 20 \mu A$; $V_{CC} = 2.0 \text{ V}$	-	0	0.1	-	0.1	٧
		$I_O = 20 \mu A$; $V_{CC} = 4.5 V$	-	0	0.1	-	0.1	٧
		$I_O = 20 \mu A$; $V_{CC} = 6.0 \text{ V}$	-	0	0.1	-	0.1	٧
		$I_{O} = 2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.33	-	0.4	٧
		$I_O = 2.6 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.33	-	0.4	٧
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	1.0	-	1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	10	-	20	μА
Cı	input capacitance			- 1.5	-	-	-	рF
For type	74HCT1G00							
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	8.0	-	0.8	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}						
	voltage	$I_O = -20 \mu A$; $V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	٧
		$I_{O} = -2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.13	4.32	-	3.7	-	٧
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}						
	voltage	$I_{O} = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	٧
		$I_O = 2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.33	-	0.4	٧
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	1.0	μΑ

 Table 7.
 Static characteristics ...continued

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

Symbol	Parameter	Conditions	-40	°C to +	85 °C	-40 °C	Unit	
			Min	Тур	Max	Min	Max	
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	10	-	20	μΑ
ΔI_{CC}	additional supply current	per input; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V};$ $V_I = V_{CC} - 2.1 \text{ V};$ $I_O = 0 \text{ A}$	-	-	500	-	850	μΑ
Cı	input capacitance		-	1.5	-	-	-	pF

11. Dynamic characteristics

Table 8. Dynamic characteristics

GND = 0 V; $t_r = t_f \le 6.0$ ns; All typical values are measured at $T_{amb} = 25$ °C. For test circuit, see Figure 6

		· · ·	arrib						
Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C 1	to +125 °C	Unit
				Min	Тур	Max	Min	Max	
For type	74HC1G00		'		'	'	'	'	
t _{pd}	propagation delay	A and B to Y; see Figure 5	[1]						
		$V_{CC} = 2.0 \text{ V}; C_L = 50 \text{ pF}$		-	25	115	-	135	ns
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		-	9	23	-	27	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	7	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$		-	8	20	-	23	ns
C_{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}$	[2]	-	19	-	-	-	pF
For type	74HCT1G00								
t _{pd}	propagation delay	A and B to Y; see Figure 5	[1]						
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		-	12	24	-	27	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	10	-	-	-	ns
C_{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC} - 1.5 \text{ V}$	[2]	-	21	-	-	-	pF

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum{(C_L \times V_{CC}{}^2 \times f_o)}$ where:

 f_i = input frequency in MHz; f_o = output frequency in MHz

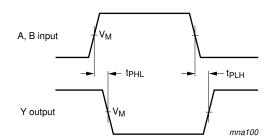
C_L = output load capacitance in pF

 V_{CC} = supply voltage in Volts

 $\sum \left(C_L \times V_{CC}{}^2 \times f_o \right)$ = sum of outputs

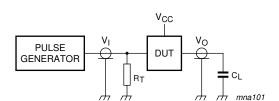
^[2] C_{PD} is used to determine the dynamic power dissipation P_D (μW).

12. Waveforms



For HC1G: V_M = 0.5 × V_{CC} ; V_I = GND to V_{CC} For HCT1G: V_M = 1.3 V; V_I = GND to 3.0 V

Fig 5. Input to output propagation delays



Test data is given in Table 8.

 C_L = Load capacitance including jig and probe capacitance.

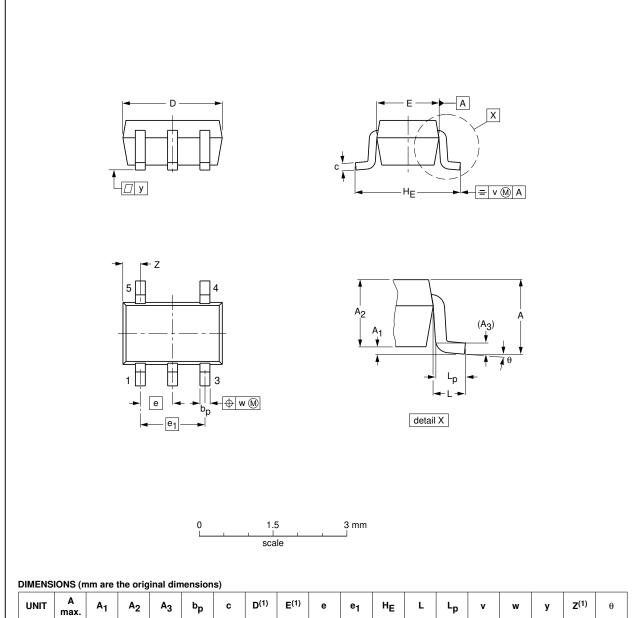
 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

Fig 6. Load circuitry for switching times

13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	HE	L	Lp	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.1 0	1.0 0.8	0.15	0.30 0.15	0.25 0.08	2.25 1.85	1.35 1.15	0.65	1.3	2.25 2.0	0.425	0.46 0.21	0.3	0.1	0.1	0.60 0.15	7° 0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DATE			
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE		
SOT353-1		MO-203	SC-88A		-00-09-01- 03-02-19		

Fig 7. Package outline SOT353-1 (TSSOP5)

74HC_HCT1G00

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Plastic surface-mounted package; 5 leads

SOT753

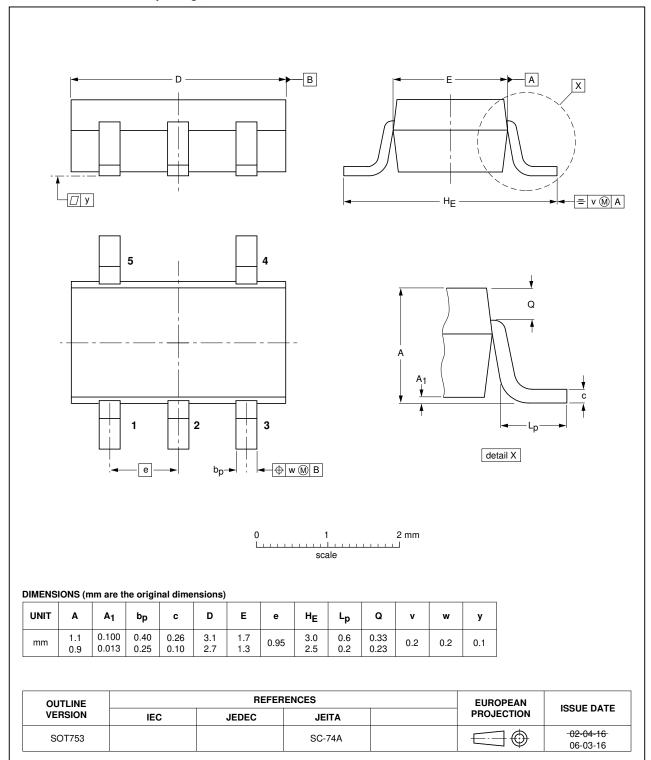


Fig 8. Package outline SOT753 (SC-74A)

14. Abbreviations

Table 9. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT1G00 v.5	20130925	Product data sheet	-	74HC_HCT1G00 v.4		
Modifications:	Section 1 "	General description" updated.				
74HC_HCT1G00 v.4	20070711	Product data sheet	-	74HC_HCT1G00 v.3		
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 					
	 Legal texts have been adapted to the new company name where appropriate. 					
	 Package SOT353 changed to SOT353-1 in <u>Section 3</u> and <u>Section 13</u>. 					
	 Quick reference data and Soldering sections removed. 					
	 Section 2 "Features and benefits" updated. 					
74HC_HCT1G00 v.3	20020515	Product specification	-	74HC_HCT1G00 v.2		
74HC_HCT1G00 v.2	20010302	Product specification	-	74HC_HCT1G00 v.1		
74HC_HCT1G00 v.1	19980730	Preliminary specification	-	-		

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Document status[1][2]	Product status[3]	Definition
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74HC_HCT1G00

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